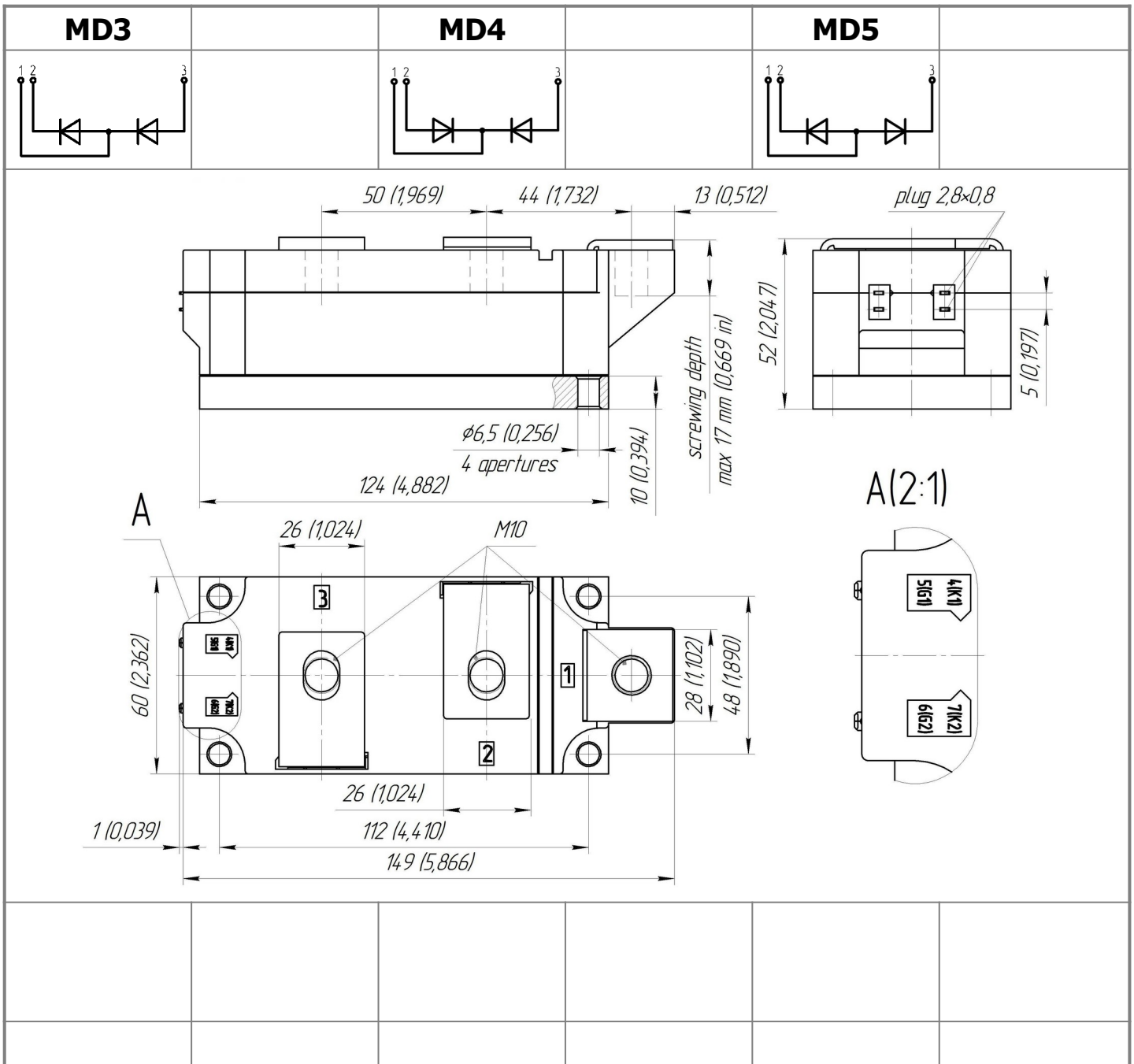




Electrically isolated base plate
 Industrial standard package
 Simplified mechanical design, rapid assembly
 Pressure contact

**Double Diode Module
 For Phase Control
 MDx-500-36-A2**

Average forward current			I_{FAV}	500 A
Repetitive peak reverse voltage			V_{RRM}	3000 ÷ 3600 V
V_{RRM}, V	3000	3200	3400	3600
Voltage code	30	32	34	36
$T_j, °C$	- 40 ÷ 150			




All dimensions in millimeters (inches)

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions
ON-STATE				
I_{FAV}	Average forward current	A	500	$T_c=102\text{ }^\circ\text{C}$; 180° half-sine wave; 50 Hz
I_{FRMS}	RMS forward current	A	785	
I_{FSM}	Surge forward current	kA	13.0 15.0	$T_j=T_{j\text{ max}}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=10\text{ ms}$; single pulse; $V_R=0\text{ V}$;
			14.0 16.0	$T_j=T_{j\text{ max}}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=8.3\text{ ms}$; single pulse; $V_R=0\text{ V}$;
I^2t	Safety factor	$A^2s\cdot 10^3$	840 1120	$T_j=T_{j\text{ max}}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=10\text{ ms}$; single pulse; $V_R=0\text{ V}$;
			810 1060	$T_j=T_{j\text{ max}}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=8.3\text{ ms}$; single pulse; $V_R=0\text{ V}$;
BLOCKING				
V_{RRM}	Repetitive peak reverse voltages	V	3000÷3600	$T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; 50 Hz;
V_{RSM}	Non-repetitive peak reverse voltages	V	3100÷3700	$T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; single pulse;
V_R	Reverse continuous voltages	V	$0.6\cdot V_{RRM}$	$T_j=T_{j\text{ max}}$;
THERMAL				
T_{stg}	Storage temperature	$^\circ\text{C}$	-40 ÷ 50	
T_j	Operating junction temperature	$^\circ\text{C}$	-40 ÷ 150	
$T_{c\text{ op}}$	Operating temperature	$^\circ\text{C}$	-40 ÷ 125	
MECHANICAL				
a	Acceleration under vibration	m/s^2	50	

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V_{FM}	Peak forward voltage, max	V	1.60	$T_j=25\text{ }^\circ\text{C}$; $I_{FM}=1256\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	0.80	$T_j=T_{j\text{ max}}$;
r_T	Forward slope resistance, max	$m\Omega$	0.500	$0.5\pi I_{FAV} < I_T < 1.5\pi I_{FAV}$
BLOCKING				
I_{RRM}	Repetitive peak reverse current, max	mA	50	$T_j=T_{j\text{ max}}$; $V_R=V_{RRM}$
THERMAL				
R_{thjc}	Thermal resistance, junction to case			180° half-sine wave, 50 Hz
	per module	$^\circ\text{C/W}$	0.0325	
	per arm	$^\circ\text{C/W}$	0.0650	
	per module	$^\circ\text{C/W}$	0.0310	
R_{thch}	Thermal resistance, case to heatsink			DC
	per module	$^\circ\text{C/W}$	0.0100	
	per arm	$^\circ\text{C/W}$	0.0200	
INSULATION				
V_{ISOL}	Insulation test voltage	kV	3.00	Sine wave, 50 Hz; RMS
			3.60	
MECHANICAL				
M_1	Mounting torque (M6) ¹⁾	Nm	6.00	Tolerance $\pm 15\%$
M_2	Terminal connection torque (M10) ¹⁾	Nm	12.00	Tolerance $\pm 15\%$
w	Weight, max	g	1500	

PART NUMBERING GUIDE						NOTES					
MD	3	-	500	-	36	-	A2	-	N		1) The screws must be lubricated
1	2		3		4		5		6		
1. MD - Rectifier Diode 2. Circuit Schematic: 3 – serial connection 4 – common Cathode 5 – common Anode 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.A2) 6. Ambient Conditions: N – Normal											
		UL certified file-No. E255404									

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